



# STTH30R03CW/CG

## HIGH FREQUENCY SECONDARY RECTIFIER

### MAJOR PRODUCT CHARACTERISTICS

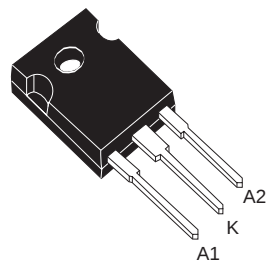
|                 |          |
|-----------------|----------|
| $I_{F(AV)}$     | 2 x 15 A |
| $V_{RRM}$       | 300 V    |
| $I_{RM} (typ.)$ | 4.5A     |
| $T_j (max)$     | 175 °C   |
| $V_F (max)$     | 1.4 V    |
| $t_{rr} (max)$  | 35 ns    |

### FEATURES AND BENEFITS

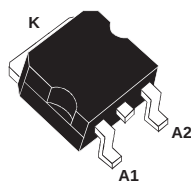
- Designed for high frequency applications.
- Hyperfast recovery competes with GaAs devices.
- Allows size decrease of snubbers and heatsinks.

### DESCRIPTION

The TURBOSWITCH "R" is an ultra high performance diode.  
This TURBOSWITCH family, which drastically cuts losses in associated MOSFET when run at high  $dI_F/dt$ , is suited for HF OFF-Line SMPS and DC/DC converters.



TO-247  
STTH30R03CW



D<sup>2</sup>PAK  
STTH30R03CG

### ABSOLUTE RATINGS (limiting values, per diode)

| Symbol              | Parameter                              |                                   |                         | Value      | Unit |
|---------------------|----------------------------------------|-----------------------------------|-------------------------|------------|------|
| V <sub>RRM</sub>    | Repetitive peak reverse voltage        |                                   |                         | 300        | V    |
| I <sub>F(RMS)</sub> | RMS forward current                    |                                   |                         | 30         | A    |
| I <sub>F(AV)</sub>  | Average forward current                | T <sub>c</sub> = 120°C<br>δ = 0.5 | Per diode<br>Per device | 15<br>30   | A    |
| I <sub>FSM</sub>    | Surge non repetitive forward current   | t <sub>p</sub> = 10 ms sinusoidal |                         | 120        | A    |
| T <sub>stg</sub>    | Storage temperature range              |                                   |                         | - 65 + 175 | °C   |
| T <sub>j</sub>      | Maximum operating junction temperature |                                   |                         | + 175      | °C   |

## THERMAL AND POWER DATA

| Symbol        | Parameter        |           | Value | Unit |
|---------------|------------------|-----------|-------|------|
| $R_{th(j-c)}$ | Junction to case | Per diode | 2.0   | °C/W |
|               |                  | Total     | 1.2   |      |
| $R_{th(c)}$   |                  | Coupling  | 0.4   |      |

## STATIC ELECTRICAL CHARACTERISTICS

| Symbol     | Parameter               | Tests conditions    |                           | Min. | Typ. | Max. | Unit          |
|------------|-------------------------|---------------------|---------------------------|------|------|------|---------------|
| $I_R^*$    | Reverse leakage current | $V_R = V_{RRM}$     | $T_j = 25^\circ\text{C}$  |      |      | 20   | $\mu\text{A}$ |
|            |                         |                     | $T_j = 125^\circ\text{C}$ |      | 30   | 200  |               |
| $V_F^{**}$ | Forward voltage drop    | $I_F = 15\text{ A}$ | $T_j = 25^\circ\text{C}$  |      |      | 1.9  | V             |
|            |                         |                     | $T_j = 125^\circ\text{C}$ |      | 1.1  | 1.4  |               |

Pulse test : \*  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$

\*\*  $t_p = 380\text{ }\mu\text{s}$ ,  $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

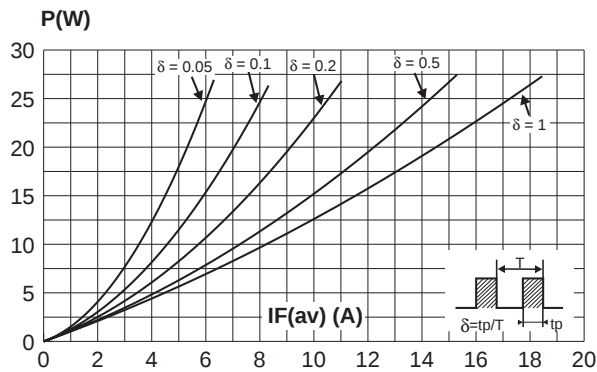
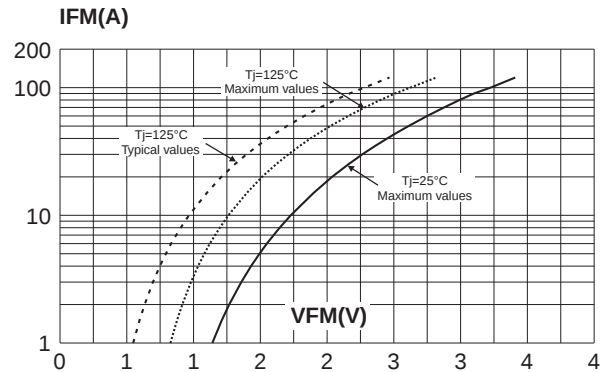
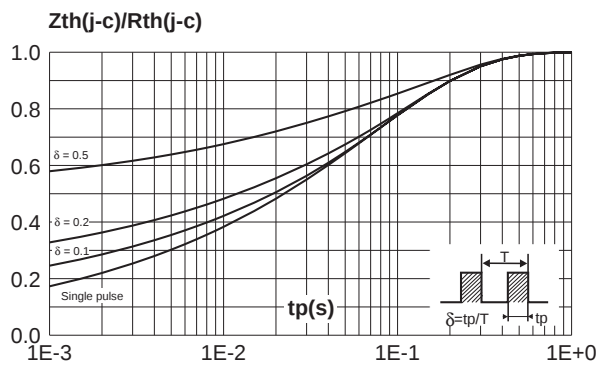
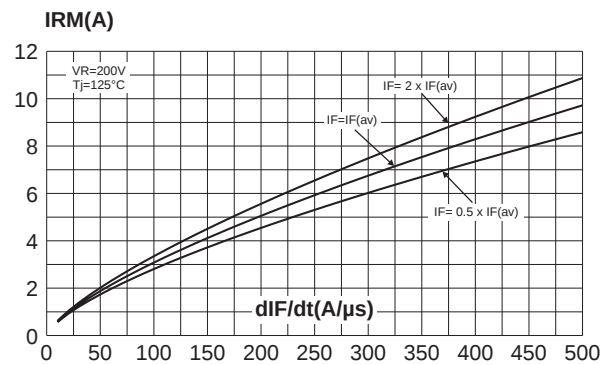
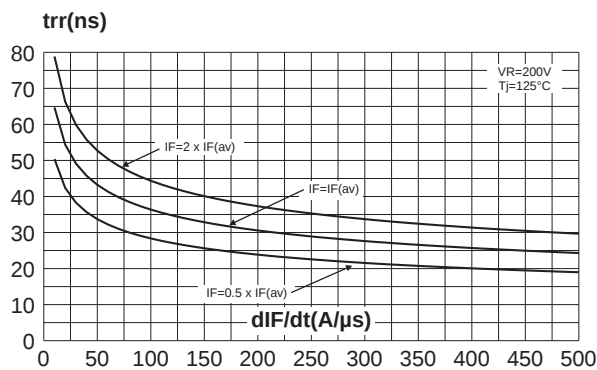
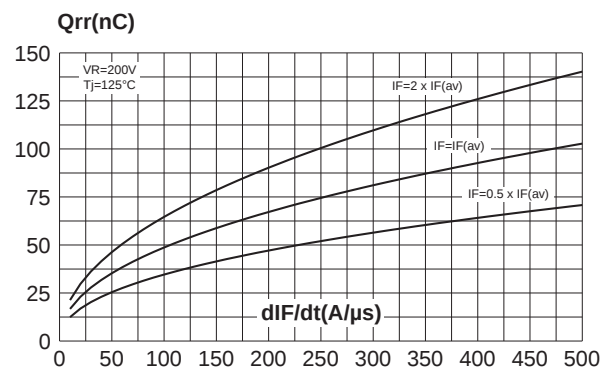
$$P = 1 \times I_{F(AV)} + 0.026 I_{F(RMS)}^2$$

## RECOVERY CHARACTERISTICS

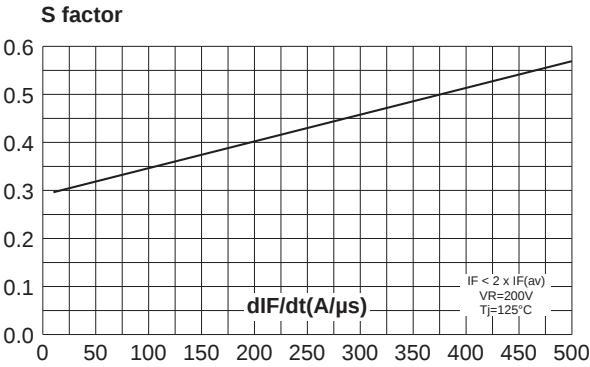
| Symbol   | Tests conditions                                                               |                           | Min. | Typ. | Max. | Unit |
|----------|--------------------------------------------------------------------------------|---------------------------|------|------|------|------|
| $t_{rr}$ | $I_F = 0.5\text{ A}$ $I_{rr} = 0.25\text{ A}$ $I_R = 1\text{ A}$               | $T_j = 25^\circ\text{C}$  |      | 20   |      | ns   |
|          | $I_F = 1\text{ A}$ $di_F/dt = -50\text{ A}/\mu\text{s}$ $V_R = 30\text{ V}$    |                           |      |      | 35   |      |
| $I_{RM}$ | $V_R = 200\text{ V}$ $I_F = 15\text{ A}$ $di_F/dt = -200\text{ A}/\mu\text{s}$ | $T_j = 125^\circ\text{C}$ |      | 4.5  | 6    | A    |
| S factor |                                                                                |                           |      | 0.4  |      |      |

## TURN-ON SWITCHING CHARACTERISTICS

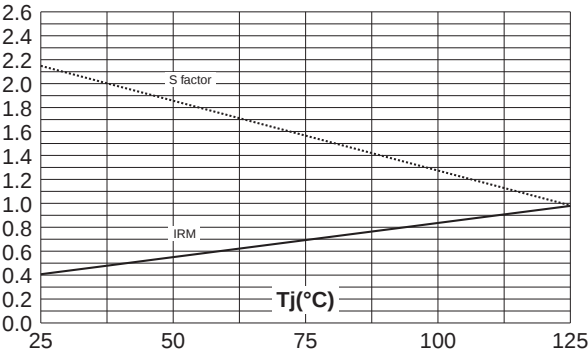
| Symbol   | Tests conditions                                                                                                       | Min. | Typ. | Max. | Unit |
|----------|------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| $t_{fr}$ | $T_j = 25^\circ\text{C}$ $I_F = 15\text{ A}$ $di_F/dt = 100\text{ A}/\mu\text{s}$<br>measured at $1.1 \times V_{Fmax}$ |      |      | 300  | ns   |
| $V_{FP}$ | $T_j = 25^\circ\text{C}$ $I_F = 15\text{ A}$ $di_F/dt = 100\text{ A}/\mu\text{s}$                                      |      |      | 3.5  | V    |

**Fig. 1:** Conduction losses versus average current**Fig. 2:** Forward voltage drop versus forward current**Fig. 3:** Relative variation of thermal impedance junction to case versus pulse duration**Fig. 4:** Peak reverse recovery current versus  $dI_F/dt$  (90% confidence).**Fig. 5:** Reverse recovery time versus  $dI_F/dt$  (90% confidence).**Fig. 6:** Reverse recovery charges versus  $dI_F/dt$  (90% confidence).

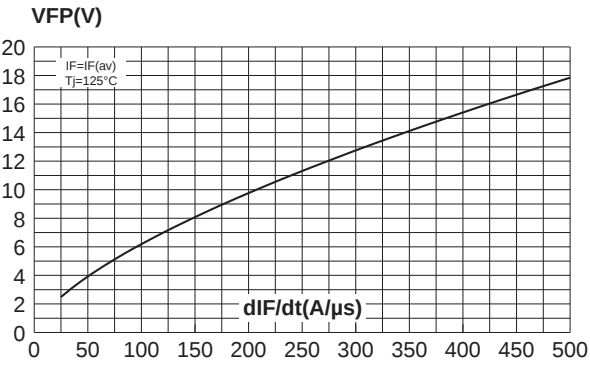
**Fig. 7:** Softness factor ( $t_b/t_a$ ) versus  $dI_F/dt$  (typical values).



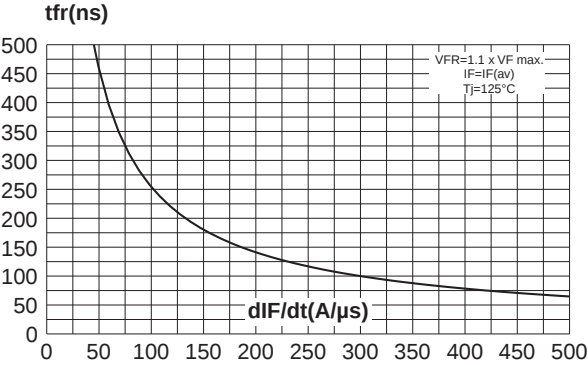
**Fig. 8:** Relative variation of dynamic parameters versus junction temperature (Reference:  $T_J = 125^\circ C$ ).



**Fig. 9:** Transient peak forward voltage versus  $dI_F/dt$  (90% confidence).

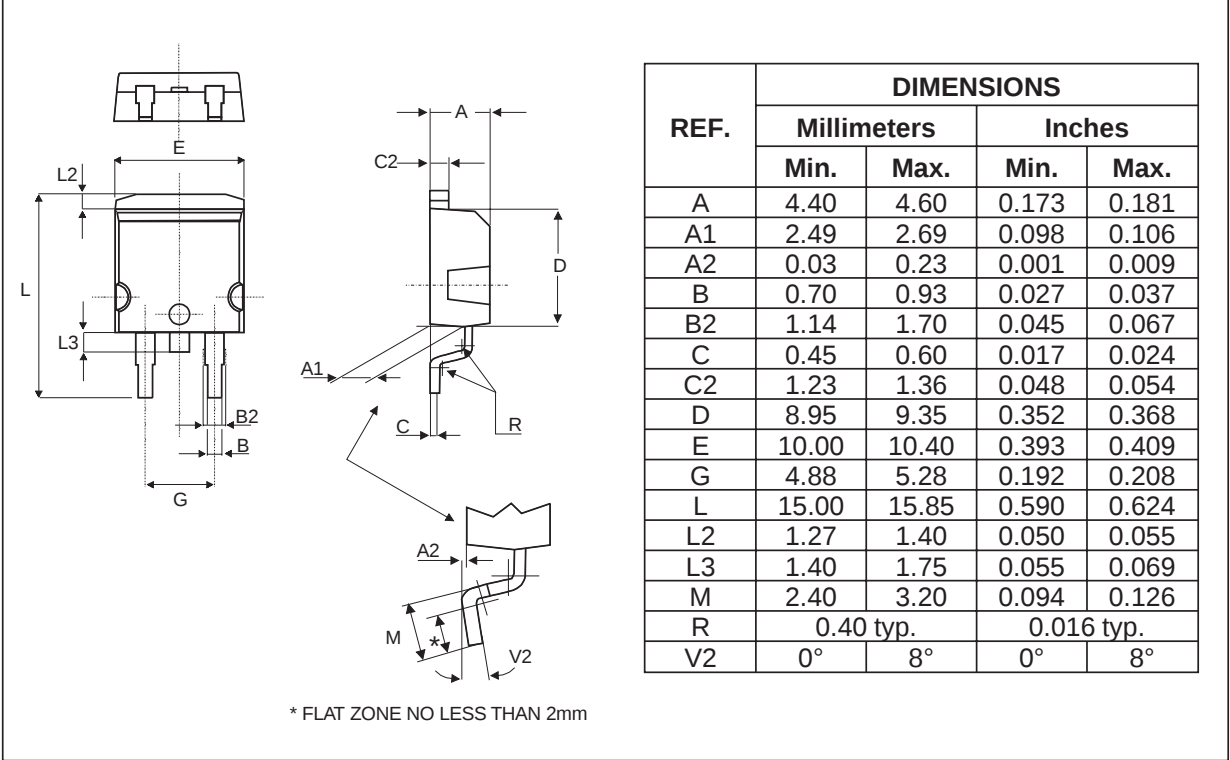


**Fig. 10:** Forward recovery time versus  $dI_F/dt$  (90% confidence).

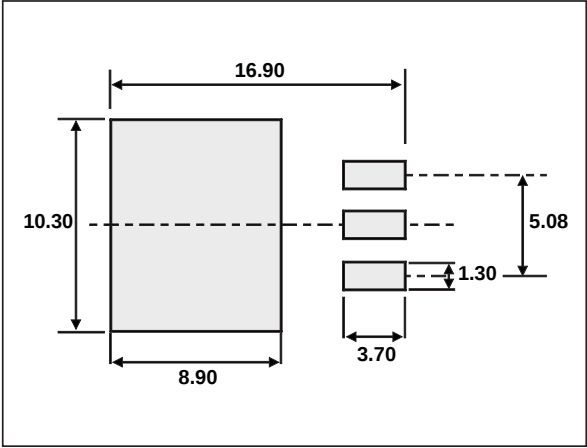


PACKAGE MECHANICAL DATA

D<sup>2</sup>PAK



FOOTPRINT



## PACKAGE MECHANICAL DATA

TO-247

| REF. | DIMENSIONS  |       |       |        |       |       |
|------|-------------|-------|-------|--------|-------|-------|
|      | Millimeters |       |       | Inches |       |       |
|      | Min.        | Typ.  | Max.  | Min.   | Typ.  | Max.  |
| A    | 4.85        |       | 5.15  | 0.191  |       | 0.203 |
| D    | 2.20        |       | 2.60  | 0.086  |       | 0.102 |
| E    | 0.40        |       | 0.80  | 0.015  |       | 0.031 |
| F    | 1.00        |       | 1.40  | 0.039  |       | 0.055 |
| F1   |             | 3.00  |       |        | 0.118 |       |
| F2   |             | 2.00  |       |        | 0.078 |       |
| F3   | 2.00        |       | 2.40  | 0.078  |       | 0.094 |
| F4   | 3.00        |       | 3.40  | 0.118  |       | 0.133 |
| G    |             | 10.90 |       |        | 0.429 |       |
| H    | 15.45       |       | 15.75 | 0.608  |       | 0.620 |
| L    | 19.85       |       | 20.15 | 0.781  |       | 0.793 |
| L1   | 3.70        |       | 4.30  | 0.145  |       | 0.169 |
| L2   |             | 18.50 |       |        | 0.728 |       |
| L3   | 14.20       |       | 14.80 | 0.559  |       | 0.582 |
| L4   |             | 34.60 |       |        | 1.362 |       |
| L5   |             | 5.50  |       |        | 0.216 |       |
| M    | 2.00        |       | 3.00  | 0.078  |       | 0.118 |
| V    |             | 5°    |       |        | 5°    |       |
| V2   |             | 60°   |       |        | 60°   |       |
| Dia. | 3.55        |       | 3.65  | 0.139  |       | 0.143 |

| Ordering code  | Marking     | Package            | Weight | Base qty | Delivery mode |
|----------------|-------------|--------------------|--------|----------|---------------|
| STTH30R03CW    | STTH30R03CW | TO-247             | 4.36g  | 30       | Tube          |
| STTH30R03CG    | STTH30R03CG | D <sup>2</sup> PAK | 1.48g  | 50       | Tube          |
| STTH30R03CG-TR | STTH30R03CG | D <sup>2</sup> PAK | 1.48g  | 1000     | Tape & Reel   |

- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N.m.
- Maximum torque value: 1 N.m.
- Epoxy meets UL 94,V0

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Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)

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